

### FEATURES

**Single-supply operation: 4.5 V to 16.5 V**  
**Upper/lower buffers swing to V<sub>S</sub>/GND**  
**Continuous output current: 35 mA**  
**V<sub>COM</sub> peak output current: 250 mA**  
**Offset voltage: 15 mV**  
**Slew rate: 6 V/μs**  
**Unity gain stable with large capacitive loads**  
**Supply current: 750 μA per amplifier**

### APPLICATIONS

**TFT LCD monitor panels**  
**TFT LCD notebook panels**  
**Communications equipment**  
**Portable instrumentation**  
**Electronic games**  
**ADC/DAC buffer**

### GENERAL DESCRIPTION

The ADD8706 is a single-supply, 5-channel buffer with a separate V<sub>COM</sub> amplifier that has been optimized for today's low cost TFT LCD notebook and monitor panels. The top and bottom channels swing to the top/bottom rails, respectively, and can be used as end-point gamma references. The middle channels are ideal for midpoint gamma references. The V<sub>COM</sub> amplifier provides very high continuous and peak currents. All channels have excellent transient response as well as high slew rate and capacitive load drive capability. The ADD8706 is specified over the -40°C to +85°C temperature range. The ADD8706 is available in a 16-lead TSSOP package.

### PIN CONFIGURATION

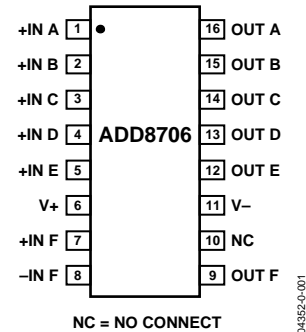


Figure 1. 16-Lead TSSOP

Table 1. Input Output Characteristics

Channel	V <sub>IH</sub>	V <sub>IL</sub>	I <sub>O</sub> (mA)	I <sub>SC</sub> (mA)
A	V <sub>S</sub>	GND + 1.7 V	15	150
B	V <sub>S</sub> - 1.7 V	GND	15	150
C	V <sub>S</sub> - 1.7 V	GND	15	150
D	V <sub>S</sub> - 1.7 V	GND	15	150
E	V <sub>S</sub> - 1.7 V	GND	15	150
F	V <sub>S</sub> - 1.7 V	GND	35	250

### Rev. 0

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

**TABLE OF CONTENTS**

Electrical Characteristics .....	3	Theory.....	9
Absolute Maximum Ratings.....	5	Input/Output Characteristics .....	9
ESD Caution.....	5	Important Note.....	9
Typical Performance Characteristics .....	6	Outline Dimensions .....	11
Application Information.....	9	Ordering Guide .....	11

**REVISION HISTORY**

Revision 0: Initial Version

## ELECTRICAL CHARACTERISTICS

Table 2.  $V_S = 16\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A @ 25\text{ }^\circ\text{C}$ , unless otherwise noted

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>SUPPLY CHARACTERISTICS</b>						
Supply Voltage	$V_S$		4.5		16	V
Power Supply Rejection Ratio	PSRR	$V_S = 4\text{ V to }17\text{ V}$ , $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	70	90		dB
Total Supply Current	$I_{SY}$	$V_O = V_S/2$ , No Load $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		4.5	5.4 6	mA mA
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$			2	15	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		10		$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		400	1100 1500	nA nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		10	100	nA
Amplifier F		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			250	nA
Common-Mode Rejection Ratio	CMRR	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$				
Amplifier F		$V_{CM} = 0$ to $(V_S - 1.7\text{ V})$	54	95		dB
Input Impedance	$Z_{IN}$			400		k $\Omega$
Input Capacitance	$C_{IN}$			1		pF
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High (A)	$V_{OH}$	$V_{IN} = 16\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		15.99		V
Optimized for High Swing		$V_{IN} = 16\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	15.75 15.65	15.85		V V
Output Voltage High (B to D)	$V_{OH}$	$V_{IN} = 14\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		14		V
Optimized for Midrange		$V_{IN} = 14\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	13.90 13.85	13.985		V V
Output Voltage High (E)	$V_{OH}$	$V_{IN} = 14\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		14		V
Optimized for Low Swing		$V_{IN} = 14\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	13.9 13.85	13.99		V V
Output Voltage High (F)	$V_{OH}$	$V_{IN} = 16\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		15.995		V
Optimized for $V_{COM}$		$V_{IN} = 16\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	15.8 15.75	15.9		V V
Output Voltage Low (A)	$V_{OL}$	$V_{IN} = 1.7\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		1.70		V
Optimized for High Swing		$V_{IN} = 1.7\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		1.71	1.730 1.725	V V
Output Voltage Low (B–D)	$V_{OL}$	$V_{IN} = 0\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		5		mV
Optimized for Midrange		$V_{IN} = 0\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		200	300 350	mV mV
Output Voltage Low (E)	$V_{OL}$	$V_{IN} = 0\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		5		mV
Optimized for Low Swing		$V_{IN} = 0\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		80	200 300	mV mV
Output Voltage Low (F)	$V_{OL}$	$V_{IN} = 0\text{ V}$ , $I_L = 100\text{ }\mu\text{A}$		5		mV
Optimized for $V_{COM}$		$V_{IN} = 0\text{ V}$ , $I_L = 5\text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		50	150 250	mV mV
Continuous Output Current (A to E)	$I_{OUT}$	$V_S = 16\text{ V}$		15		mA
Continuous Output Current (F)	$I_{OUT}$	$V_S = 16\text{ V}$		35		mA
Peak Output Current (A to E)	$I_{PK}$	$V_S = 16\text{ V}$		50		mA
Peak Output Current (F)	$I_{PK}$	$V_S = 16\text{ V}$		200		mA

# ADD8706

Parameter	Symbol	Condition	Min	Typ	Max	Unit
TRANSFER CHARACTERISTICS						
Amplifier Gain	$A_{vo}$	$R_L = 2\text{ k}\Omega, V_o = 0.5\text{ to } (V_s - 2\text{ V})$	1	10		V/mV
Buffer Gain	$A_{vcl}$	$R_L = 2\text{ k}\Omega$	0.995	0.9985	1.005	V/V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	0.995	0.9980	1.005	V/V
Buffer Gain Linearity	NL	$R_L = 2\text{ k}\Omega, V_o = 0.5\text{ to } (V_s - 0.5\text{ V})$		0.01		%
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega, C_L = 200\text{ pF}$	4	6		V/ $\mu\text{s}$
Bandwidth	BW	$-3\text{ dB}, R_L = 2\text{ k}\Omega, C_L = 40\text{ pF}$		6		MHz
Phase Margin	$\phi_o$	$R_L = 2\text{ k}\Omega, C_L = 40\text{ pF}$		55		Degrees
Channel Separation				75		dB
NOISE PERFORMANCE						
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		26		nV/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		25		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 10\text{ kHz}$		0.8		pA/ $\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

Table 3. ADD8706 Stress Ratings\*

Parameter	Rating
Supply Voltage ( $V_s$ )	18 V
Input Voltage	-0.5 V to $V_s + 0.5$ V
Differential Input Voltage	$V_s$
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-40°C to +85°C
Junction Temperature Range	-65°C to +150°C
Lead Temperature Range	300°C
ESD Tolerance (HBM)	±1500 V

\*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

Table 4. Package Characteristics

Package Type	$\theta_{JA}$ <sup>1</sup>	$\theta_{JC}$	Unit
16-Lead TSSOP (RU)	180	35	°C/W

<sup>1</sup> $\theta_{JA}$  is specified for worst-case conditions, i.e.,  $\theta_{JA}$  is specified for devices soldered onto a circuit board for surface-mount packages.



TYPICAL PERFORMANCE CHARACTERISTICS

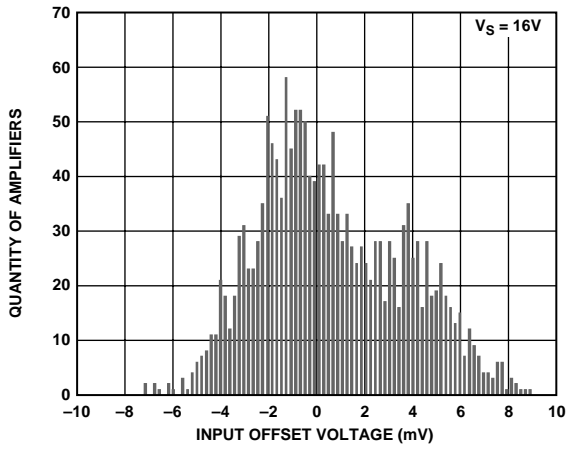


Figure 2. Input Offset Voltage,  $V_S = 16\text{ V}$

04352-0-025

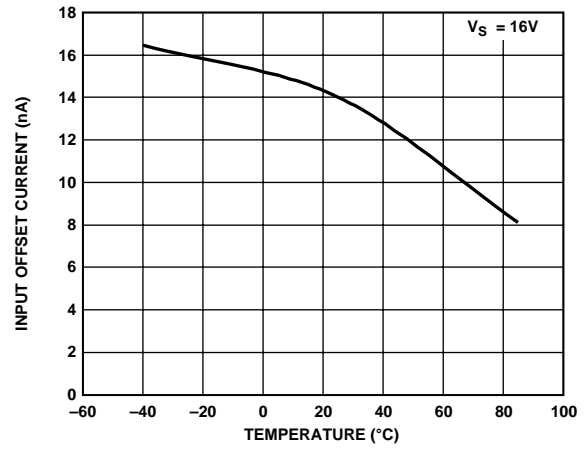


Figure 5. Input Offset Current vs. Temperature

04352-0-028

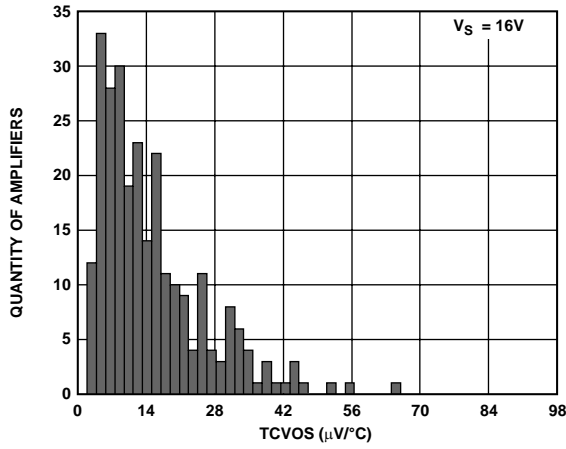


Figure 3. Input Offset Voltage Drift,  $V_S = 16\text{ V}$

04352-0-026

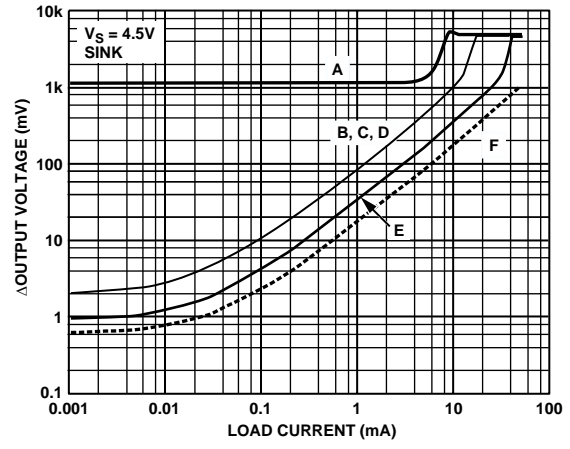


Figure 6. Output Sink Voltage vs. Load Current, All Channels

04352-0-013

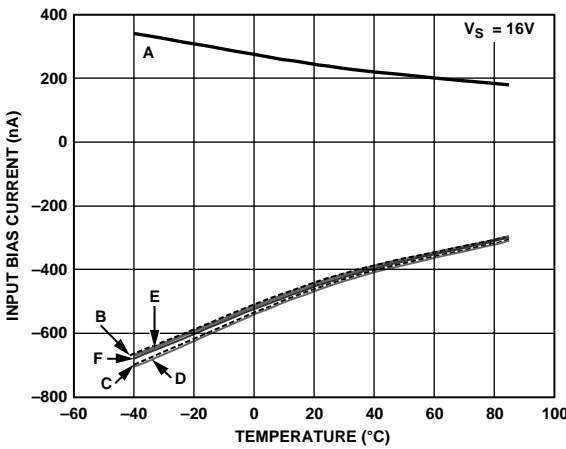


Figure 4. Input Bias Current vs. Temperature

04352-0-027

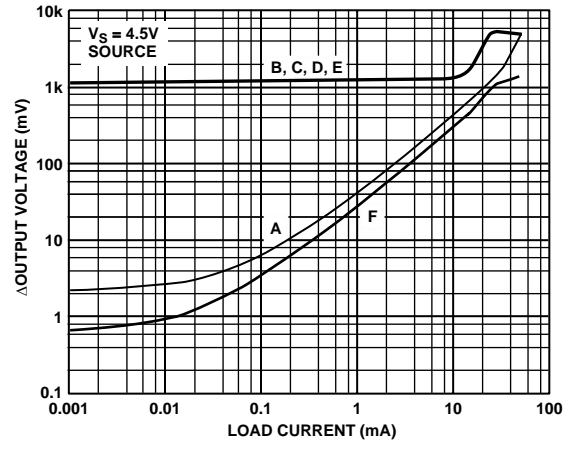


Figure 7. Output Source Voltage vs. Load Current, All Channels

04352-0-015

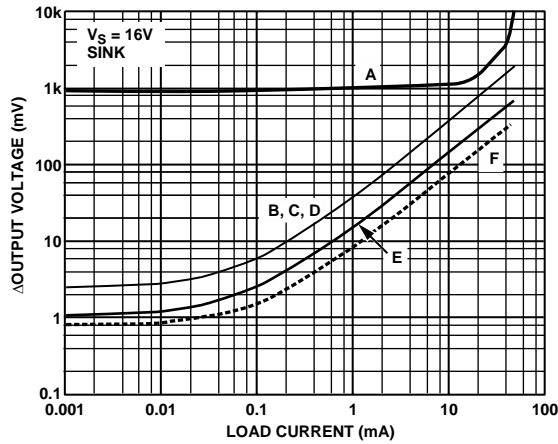


Figure 8. Output Sink Voltage vs. Load Current, All Channels

04352-0-014

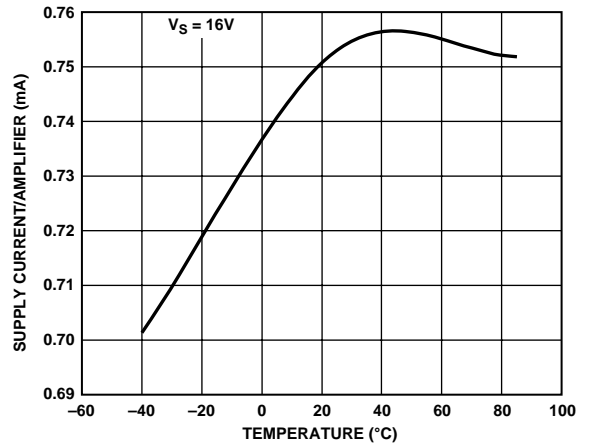


Figure 11. Supply Current vs. Temperature

04352-0-029

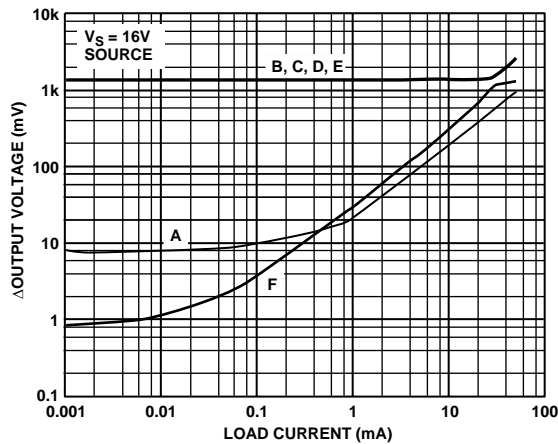


Figure 9. Output Source Voltage vs. Load Current, All Channels

04352-0-016

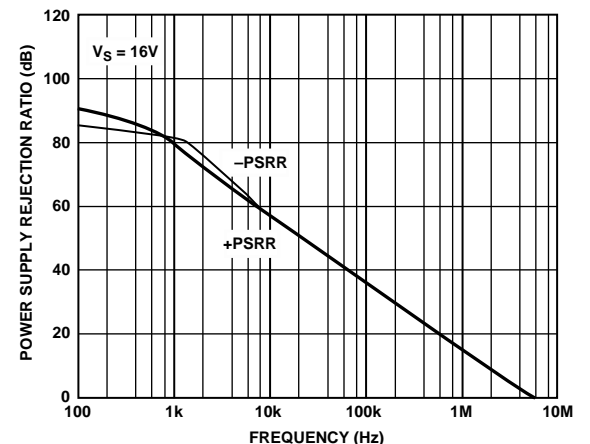


Figure 12. PSRR vs. Frequency

04352-0-018

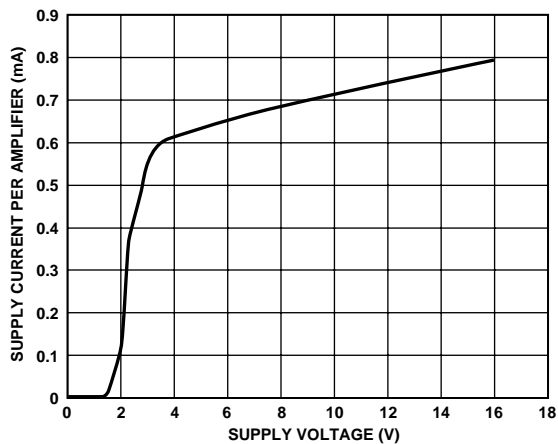


Figure 10. Supply Current vs. Supply Voltage

04352-0-022

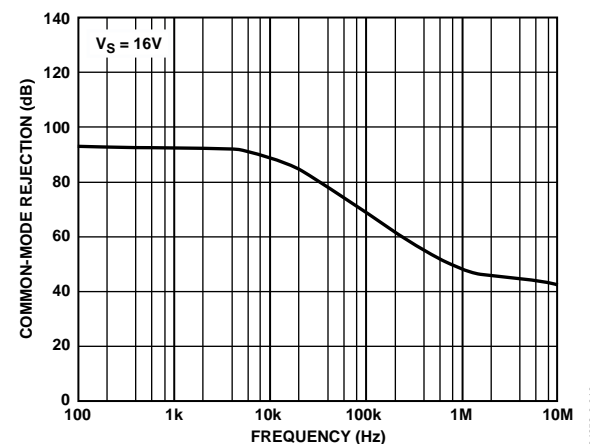


Figure 13. CMRR vs. Frequency

04352-0-010

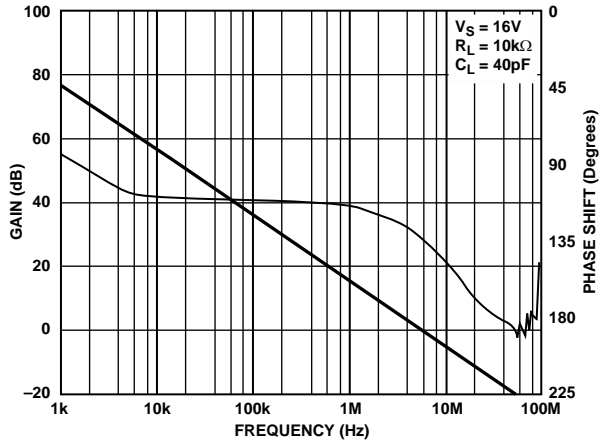


Figure 14. Frequency vs. Gain and Shift

04352-0-012

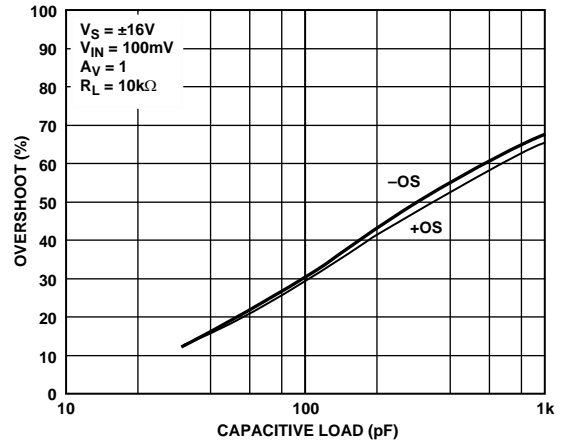


Figure 17. Overshoot vs. Capacitive Load

04352-0-020

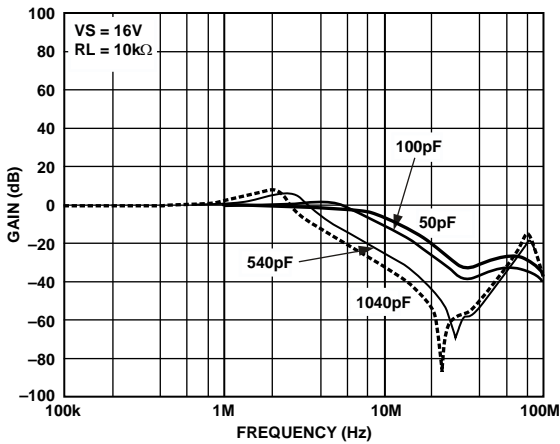


Figure 15. Gain vs. Capacitive Load

04352-0-008

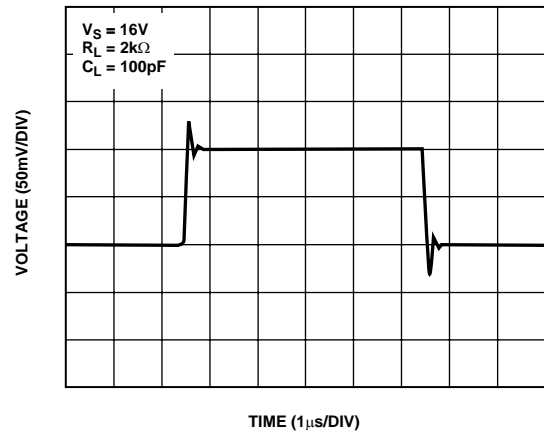


Figure 18. Small-Signal Transient Response

04352-0-021

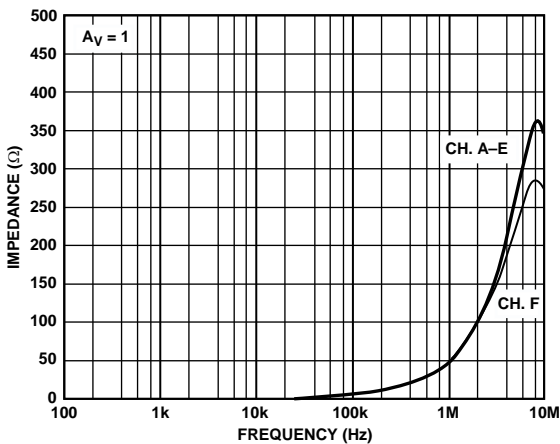


Figure 16. Impedance vs. Frequency

04352-0-005

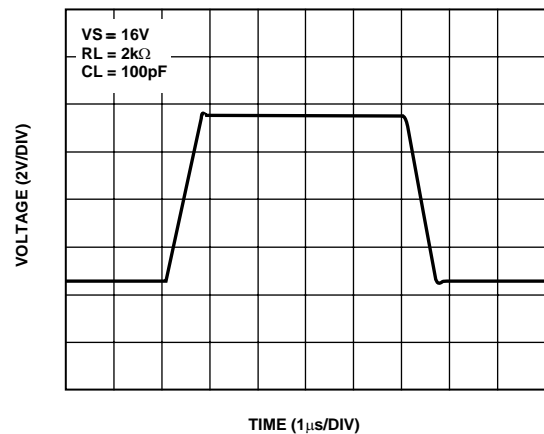


Figure 19. Large Signal Transient Response

04352-0-013



## APPLICATION INFORMATION

### THEORY

The ADD8706 is designed for use in LCD gamma correction circuits. This is an ideal on-chip solution for low-end panels. It provides five gamma voltages and a  $V_{COM}$  output. These gamma voltages provide the reference voltages for the column driver RDACs. Due to the capacitive nature of LCD panels, it is necessary for these drivers to provide high capacitive load drive.

The  $V_{COM}$  output is the center voltage common to all the LCD pixels. The  $V_{COM}$  circuit is common to all the pixels in the panel. This requires the  $V_{COM}$  driver to supply continuous currents up to 35 mA.

### INPUT/OUTPUT CHARACTERISTICS

The ADD8706 has five buffers specifically designed for the needs of an LCD panel. Figure 20 shows a typical gamma correction curve for a normally white twisted nematic LCD panel. The symmetric curve comes from the need to reverse the polarity on the LC pixels to avoid “burning” in the image. Therefore, the application requires gamma voltages that come close to both supply rails. To accommodate this transfer function, the five ADD8706 buffers have been designed with three different buffer designs in one package.

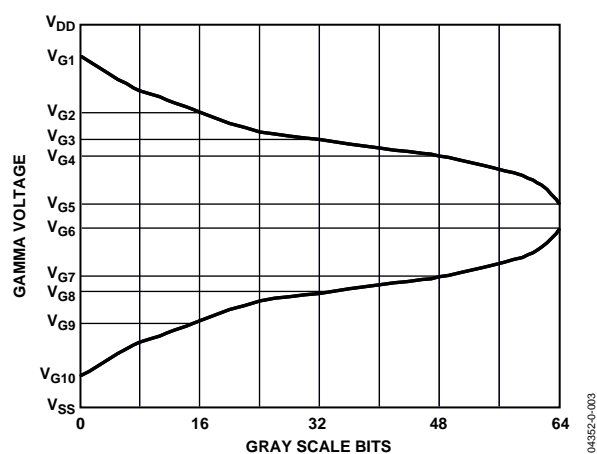


Figure 20. LCD Gamma Correction Curve

The nature of LCD panels introduces a large amount of parasitic capacitance from the column drivers as well as the capacitance associated with the liquid crystals via the common plane. This makes capacitive drive capability an important factor when designing the gamma correction circuit.

The outputs of the buffers and amplifier have been designed to match the performance needs of the gamma correction and  $V_{COM}$  circuits. All have rail-to-rail outputs, but the current drive capabilities differ. The difference in current drive and input voltage range determine the buffer and amplifier use.

Buffer A has an NPN emitter-follower input stage, which provides an input range that includes the top rail, but is limited to 1.7 V away from the bottom rail. It is designed to source 15 mA of continuous current, making this buffer ideal for providing the top voltage on the RDAC string.

Buffers B, C, and D use a single-supply PNP input stage with an intermediate common-mode voltage range. The output was designed to sink or source up to 15 mA of continuous current. The limited input range and equivalent sink and source current make these buffers suitable for the middle voltage ranges on the RDAC string.

Buffer E also uses a single-supply PNP input stage, but the output is designed to sink only up to 15 mA of continuous current. This buffer is designed for the RDAC's lower range.

Amplifier F is designed with an input range limited to midscale applications. It is capable of delivering 35 mA of continuous current. These qualities make Amplifier F suitable for  $V_{COM}$  applications.

### IMPORTANT NOTE

Because of the asymmetric nature of Buffers A and E, care must be taken to connect an input that forces the amplifiers to operate in their most productive output states. Buffer A has very limited sink capabilities, while Buffer E does not source well. Set the Buffer A input to enable the amplifier output to source current and set the Buffer E input to force a sinking output current. This means making sure the input is above the midpoint of the common-mode input range for Buffer A and below the midpoint for Buffer E. Mathematically speaking, make sure  $V_{IN} > V_S/2$  for Buffer A and  $V_{IN} < V_S/2$  for Buffer E.

Figure 21 shows an application using the ADD8706 to generate 10 gamma outputs. Note that the five outputs are routed through another resistor network to generate the extra five output voltages, which feed into the column driver.

# ADD8706

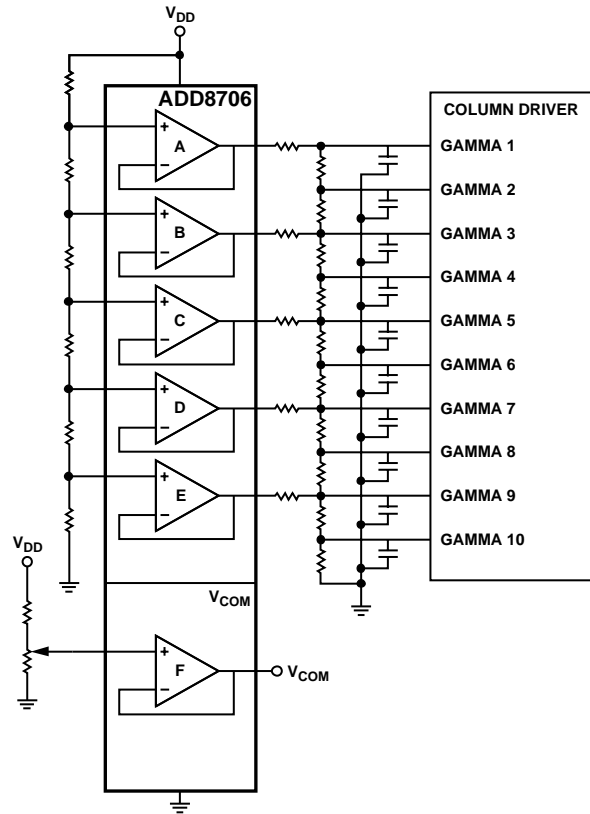
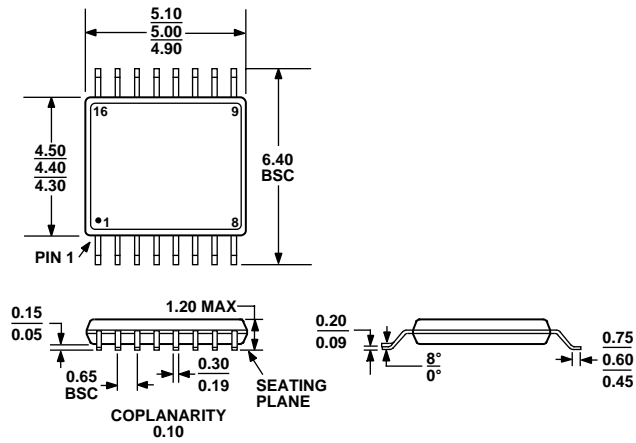


Figure 21. ADD8706 Application Circuit

000004-000

# OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153AB

Figure 22. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU)  
Dimensions shown in millimeters

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option
ADD8706ARUZ	-40°C to +85°C	16-Lead TSSOP	RU-16
ADD8706ARUZ-REEL	-40°C to +85°C	16-Lead TSSOP	RU-16

<sup>1</sup> Z = Pb-free part.

**ADD8706**

**NOTES**